



# Practically achievable WLTC loss improvements for the Si/SiC hybrid switch approach in a 400 V automotive traction inverter application – A retrofitting case study

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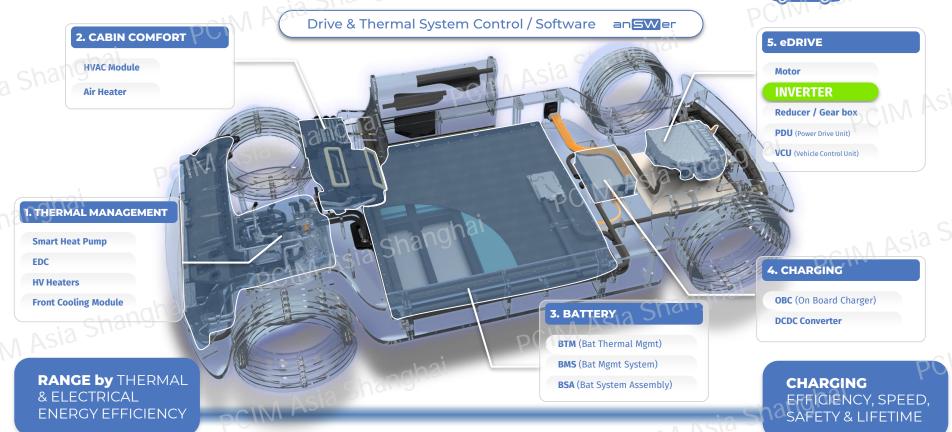
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### POWERTRAIN & THERMAL SYSTEM FUSION FOR COST & EFFICIENCY = 6 4





Figures as at December 31st, 2024 \*R&D = Research & Development Centers PCIM Asia Shangi is

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### HYBRID SWITCHshangha

Introduction & scope M Asia Shanghai

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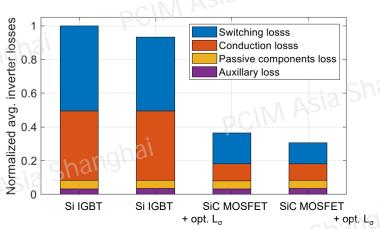
### Introduction

State of the art

### SIC as the new PCOLD STANDARD

Typically SiC MOSFETs reduce inverter losses by ~60 ... 70 %

Exemplary WLTC inverter loss distribution for a c segment vehicle



Source: A. Rambetius et al., "Efficiency Trends for Electric Traction Drives", 32<sup>nd</sup> Aachen Colloquium Sustainable Mobility, 2023





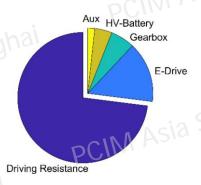




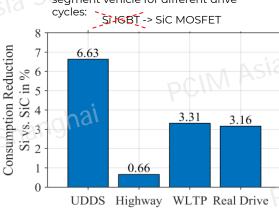
### System BENEFITS

Even though impact of SiC upgrade on power electronics is huge, inverter losses are weighted with losses from other components

Exemplary WLTC drivetrain loss distribution for a c segment vehicle:



Exemplary WLTC vehicle consumption reduction of a d segment vehicle for different drive



Source: A. Nisch et al., "Simulation and Measurement-Based Analysis of Efficiency Improvement of SiC MOSFETs in a Series-Production Ready 300 kW / 400 V Automotive Traction Inverter", 22<sup>nd</sup> European Conference on Power Electronics and Applications, 2020

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### Scope

Si/SiC hybrid switch retrofitting







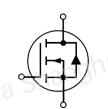


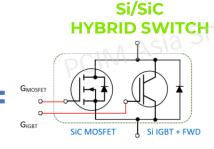
#### Si IGBT & FWD

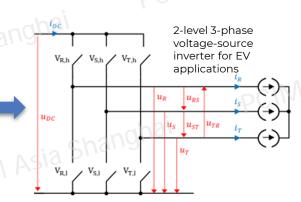




### **SIC MOSFET**







#### Bipolar devices

- + high ampacity
- slow/lossy switching
- stored charges
- part-load voltage drop
- + EMI-friendly

#### Area/cost ratio

- + cost-effective
- large footprint

#### Unipolar device

- medium ampacity
- + fast/efficient switching
- + negligible charges
- resistive voltage drop
- pronounced ringing

### Area/cost ratio

- pricey
- + small footprint

### Practically achievable PERFORMANCE?

- Retrofit implementation in series-production automotive traction inverter 400 V / 150 kW
- Realistic switching speeds
- WLTC usage
- Thermal equilibrium
- Benchmarking vs. full Si and full SiC

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Characterization & simulation

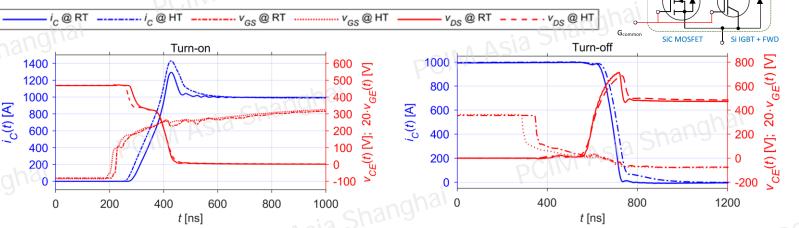
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### **Dynamic characterization**

Switching performance common gate







Double-pulse test conditions:

 $V_{dc} = 470 \text{ V}$  $I_1 = 1000 A$  $T_{vi}$  = 25 °C (RT)  $T_{vi} = 175 \,^{\circ}\text{C} \text{ (HT)}$ 

### Switching performance COMMON gate

- Clean switching waveforms
- Coverage of full dynamic load range
- Very good harmony btw. dyn characteristics of different devices mandatory
- Switching loss reduction < 50 % vs. full SiC

E<sub>sw,tot</sub> [a. u.] 8.0 9.0 8.0 7.0 8.0 8.0 600 700 800 900 200 300 500

Si/SiC Hybrid switch

Si IGBT SIC MOSFET

 $T_{vj} = 25 \,^{\circ}\text{C} \, \& \, V_{dc} = 400 \,^{\circ}\text{V}$ 

### Simulation model

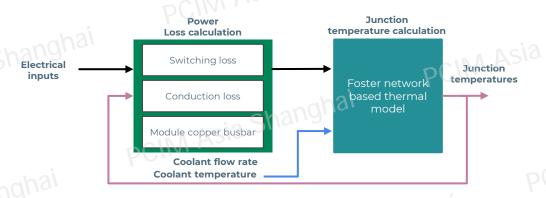
IPCEI Microelectronics and Communication Technologies







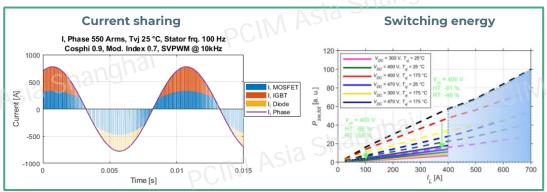
# Power module model description Shangha



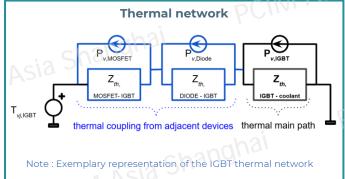
### Myanced model for hybrid simulation of:

- Semiconductor power loss
- Individual junction temperature

#### Power loss calculation



#### **Junction temperature calculation**



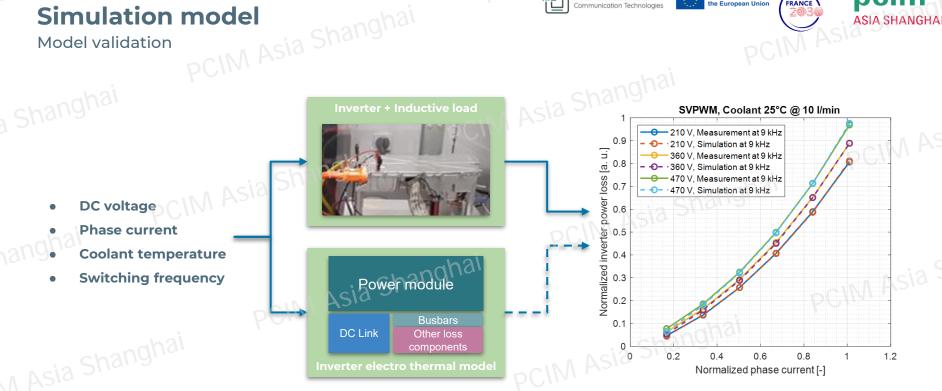
### Simulation model







Model validation



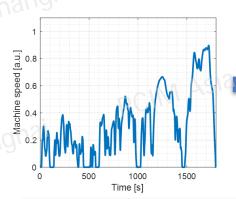
The comparison reveals evacuement agreement between measurements and simulations.

### CIM Asia Shangha. **WLTC** simulation

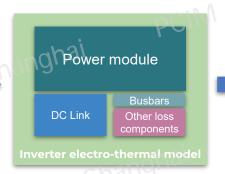
Class C/D vehicle



for class C/D vehicle



### **Simulation**



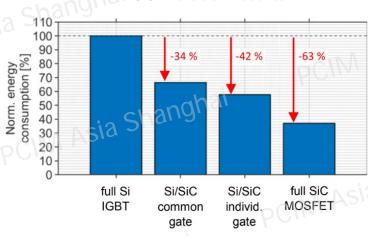
Si/SiC hybrid switch brings about 54% of Neduction in energy consumption achievable with SiC MOSFET power module Asia Shanghai with common gate control.







#### **WLTC Simulation results**



### **Boundary conditions**

DC voltage :360 V

Modulation : SVPWM @ 10

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Coolant temperature : 65 °C PCIM Asia Shang Coolant flow

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### HYBRID SWITCHshangha

Test bench measurements

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### Motor test bench measurement

Measurement set up





### Si IGBT and Si/SiC hybrig(n) test bench

Identical measurement setup, thermal conditions for inverter and motor were maintained to achieve SchM Asia Shangha a fair comparison.

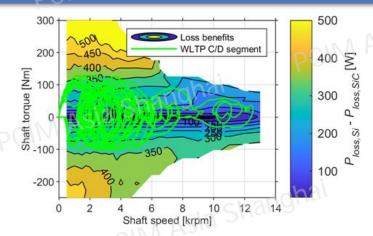








- Constant torque speed maps with defined stator and rotor temperatures were measured
- A multitude of consecutive WLTC cycles were measured with defined thermal starting conditions



### Motor test bench measurement



Motor



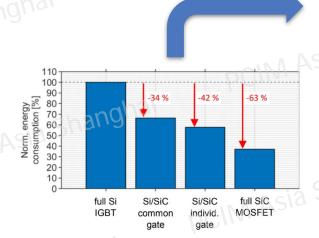


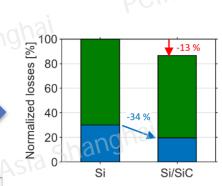


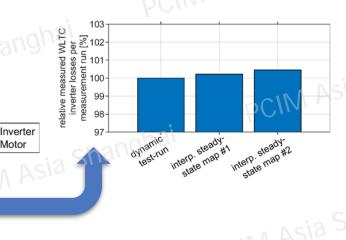
Measurement results

## mulation results

The measurement results show identical loss improvement of 34 % on inverter level







High reproducibility ensures reliable and comparable test results, which is crucial for accurate performance validation.

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### HYBRID SWITCHshangha

Performance & conclusion

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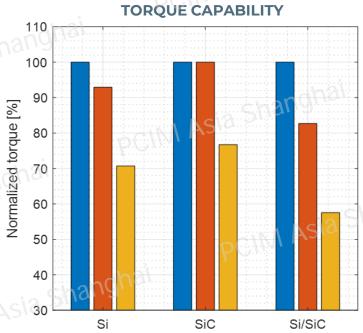
# Performance outlook chandhal







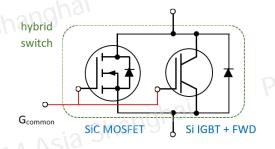






### **Boundary conditions**

DC voltage : 470 V
Modulation : SVPWM
Coolant temp.: 65 °C
Coolant flow : 81/min



Operation <i>mode</i>	Performance limited by
Motoring mode	si IGBT / AS
Regenerative mode	Si Diode
Stand still	Si Diode

Increasing the die area to satisfy the application's regenerative torque requirements is a tradeoff between torque capability and efficiency.

### **Summary**









The hybrid switch: from theory to proven performance

### HARMONY

Hybrid switch requires most careful selection of dynamic and static characteristics



- Hard parallel operation feasible
- SiC content significantly reducing switching and part-load conduction losses
- Further efficiency gains with individual gate control

### **PREDICTION**

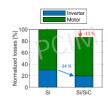
Hybrid switch requires advanced modelling due to complex electrical & thermal interaction



- Side-by-side eDrive test results fully align with predicted improvements
- 34 % reduction in inverter losses confirmed on real-world set-up

### **IMPACT**

Hybrid switch with compelling efficiency boost compared to full Si-IGBT



- Retrofitting offers ½ reduction of eDrive losses
- "In-between solution" compared to full SiC for WLTC efficiency
- Achievable regen braking and standstill performance require special attention

Enriched with hybrid switch technology, VALEO's comprehensive inverter portfolio offers customers an 4plaste cost-performance ratio and future-proof integration.

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